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Article:

Marrows, CH orcid.org/0000-0003-4812-6393 and Zeissler, K (2021) Perspective on skyrmion spintronics. Applied Physics Letters, 119 (25). 250502. ISSN 0003-6951

https://doi.org/10.1063/5.0072735

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Perspective on skyrmion spintronics

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(Dated: 25 November 2021)

Magnetic skyrmions are attractive for representing data in next-generation spintronic devices owing to their stability, small size, and ease of manipulation with spin torques. In order to realize such devices, it is necessary to be able to write, manipulate, and read back data by means of nucleating, propagating, and detecting skyrmions using an allelectrical approach. Here we review the basic concepts underpinning magnetic skyrmions, describe our recent results on their electrical nucleation, propagation, and detection, and offer some perspectives for future research in this vibrant field.

I. INTRODUCTION

Magnetic skyrmions are topologically non-trivial spin textures with particle-like properties. Skyrme originally introduced the idea of a topological soliton as a model of a particle in high-energy physics¹, but this concept has found utility in many branches of physics including condensed matter². Originally predicted theoretically to be stabilized by the Dzyaloshinkii-Moriya interaction (DMI)³, skyrmions were first observed at low temperatures in the chiral magnetic materials MnSi⁴ and Fe_{0.5}Co_{0.5}Si⁵ and atomic monolayers in which the DMI is generated at the interface6.

Magnetic skyrmions are now routinely observed at room temperature. This can either be in bulk materials in which they are stabilized by a DMI⁷ or frustration⁸, or in magnetic multi-layers that possess interfacial DMI^{9–12}. They are also known to respond to spin-transfer^{13,14} and spin-orbit torques^{15,16}, and so can be electrically manipulated, opening up the prospect of skyrmion-based spintronic devices.

There are several recent reviews that cover different aspects of this very active field17-25, as well as a recently published skyrmion roadmap²⁶. In this perspective we focus on spintronic aspects of skyrmions, especially those in magnetic multilayers with interfacial DMI. After giving some general background to introduce the main concepts, we review our own contributions to the field in the context of the work of others. and then conclude by giving our outlook for the future.

II. BACKGROUND

A magnetic skyrmion is a localized spin texture with a form like that shown in Fig. 1. Strictly, it has a point-like core that is oppositely magnetized to the spins around the edge, whose uniform magnetization allow it to be embedded in a uniformly magnetized magnetic material or else form lattices^{4,5}. Surrounding the core is a splay or swirl of spins that cover every direction in space. In fact, in thin films the core is often a small uniformly magnetized region-a circular reversed domain-that is surrounded by a 'swirling' domain wall. Such structures are sometimes referred to as skyrmion bubbles in reference to



FIG. 1. Spin textures for (a) Néel-type and (b) Bloch-type skyrmions. The core (blue) points in the opposite direction to the edge (red). A spin pointing in every direction in space can be found somewhere within the skyrmion. Reproduced under CC-BY license from Ref. 30

bubble domains which lack the 'swirling' domain wall. Nevertheless, in this Perspective we shall term all such structures skyrmions since they are topologically equivalent. The form and sign of the DMI enforces the nature and chirality of the domain wall around the core. Usually in bulk DMI materials the skyrmions have a Bloch structure (Fig. 1(b)), whereas interfacial DMI leads to a Néel structure (Fig. 1(a)). Skyrmion diameters range from the nm to the µm scale, although several tens or a few hundred nm are typical. In thin films the skyrmions do have the disc-like character shown in the figure. whilst in three dimensional bulk materials they extend into tubes27-29

The topological nature of the skyrmion is captured mathematically by the winding number S defined as

$$S = -\frac{1}{4\pi} \int \mathbf{\hat{m}} \cdot (\partial_x \mathbf{\hat{m}} \times \partial_y \mathbf{\hat{m}}) \, dx dy, \tag{1}$$

where $\hat{\mathbf{m}}$ is a unit vector in the direction of the local magnetization and the skyrmion occupies the x-y plane. This takes a value of S = 1 for an object with skyrmion topology, distinct from the value of S = 0 for a uniformly magnetized or otherwise topologically trivial state. The requirement to make the jump between discrete values of S to create or annihilate a skyrmion in an otherwise uniformly magnetized material provides a weak form of topological protection to skyrmions, enhancing their stability. It is not possible to smoothly deform one state into the other. A geometric interpretation of S is the

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number of times a sphere in spin space is completely wrapped by the spin texture in question. A good recent discussion of the various forms of topological protection for different types of skyrmion materials can be found in Ref. 31.

The winding number also represents the topological charge of the spin texture, which takes discrete integer values. As electrons pass through spin textures they acquire a Berry phase³², which will, as a result, be quantized. This Berry phase can be viewed as giving rise to an emergent magnetic flux acting on the electrons³³, which turns out to be quantized in units of the flux quantum, $\Phi_0 = h/e$. In a skyrmion lattice with unit cell of area A we can then write the emergent flux density as $B_e = S\Phi_0/A$. It is important to note that whilst this emergent flux density is a mathematical concept necessary to take account of the Berry phase, it nevertheless exerts a Lorentz force on the conduction electrons. This force then gives rise to a contribution to the transverse resistivity known as the topological Hall effect^{34,35}, which can be written as $\rho_{xy} = R_{\rm H} P B_{\rm e}$, where $R_{\rm H}$ is the ordinary Hall coefficient and P is the spin polarization of the current. Hall signals of this sort have been used as evidence for the presence of a skyrmion lattice in MnSi³⁶⁻³⁸. A further aspect to this emergent electrodynamics is that once the skyrmions are set in motion, such as by a spin-torque exerted by the current, an emergent electric field is generated that is given in analogy to Faraday's law of induction by $\mathbf{E}_e = -\mathbf{v}_d \times \mathbf{B}_e$, where \mathbf{v}_d is the drift velocity of the skyrmions. This provides a Hall voltage opposite in sign to that generated by the topological Hall effect, and will completely cancel it once the skyrmions are drifting at same velocity as the current-carrying electrons39

Since skyrmions are rigid particle-like objects their dynamics is amenable to modeling using a modified form of the Thiele equation^{17,33}, which for spin-orbit torques can be written as⁴⁰

$$\mathbf{G} \times \mathbf{v}_{\mathrm{d}} + \alpha \mathscr{D} \times \mathbf{v}_{\mathrm{d}} + 4\pi \mathscr{B} \cdot \mathbf{J}_{\mathrm{hm}} = 0, \qquad (2)$$

where $\mathbf{G} = (0, 0, -4\pi S)$ is the gyromagnetic coupling vector that is directly coupled to the presence of topological charge. In the dissipation term α is the Gilbert damping coefficient and \mathcal{D} is a dissipative force tensor, whilst in the spin-orbit torque term \mathscr{B} is a tensor that quantifies the efficiency of the spin-orbit torque over the skyrmion texture whilst $\mathbf{J}_{hm} = \mathbf{J}_s / \theta_{sh}$ is the electrical current density flowing in the heavy metal that provides the spin-orbit torque by means of the spin Hall effect with spin Hall angle θ_{sh} leading to a spin current density J_s . The presence of a gyrovector with finite value means that a skyrmion experiences a transverse Magnus force in addition to a driving force along the current direction, leading to motion at an angle to the driving force. This phenomenon is known as the skyrmion Hall effect and is quantified by the spin Hall angle Θ_{sk} . This skyrmion Hall effect has been directly observed in multilayer systems with spin-orbit torque driven skyrmion motion^{40,41}

The fact that skyrmions are small, stable, and respond to spin-polarized currents mean that they are promising candidates for skyrmion spintronic devices. Understanding the mechanisms of creating, propagating, and detecting magnetic skyrmions at room temperature in devices by all-electrical means is an important stepping stone towards realizing novel applications. In the next section we review our recent results on these three topics.

III. RECENT RESULTS

A. Nucleation

The room temperature stability and magnetic field-induced nucleation of skyrmions in interfacial DMI heterostructures are well-documented and are controlled by a balance of magnetic energy terms (exchange, DMI, anisotropy, Zeeman and magnetostatic)^{10,11}. However, in real world devices it is not only such materials properties but also defects and inhomogeneities which play an important role⁴². The development of practical devices requires the controlled nucleation skyrmions at defined points of interest. Numerical investigations demonstrated the possibility of spin-polarized currents injected vertically as means to electrically nucleate individual skyrmions in nanostructures43, a concept later expanded upon using a point contact via micromagnetic simulations⁴⁴. Experimentally, it was shown that divergent currents $(J \sim 10^9 - 10^{10} \text{ Am}^{-2})$ combined with a small out-of-plane magnetic field can be used to create skyrmions at the point where the constriction expands into a wider wire. If the constriction is made from the same magnetic material the nucleation mechanism is analogous to bowing soap bubbles, in so far, that the domains are pushed through the constriction by the current, expand as they leave the constriction and then pinch off into skyrmions¹² (see Fig. 2(a)). A more chaotic and less predictable creation mechanism is the electrical nucleation from random defects in nanostructures which was observed by various groups in $2018^{45\text{--}47}$ (see Fig. 2(b)). In bulk systems electrical nucleation has been demonstrated at current densities three magnitudes lower⁴⁸. Hrabec *et al.* showed the first experimentally deterministic nucleation from a non-magnetic point contact driven by the divergence of current lines, heating, and spin accumulation at the tip which results in the local reversal of the magnetic configuration near the tip^{49,50} (see Fig. 2(c)).

Our work in 2019 took advantage of this idea to demonstrate the all-electrical nucleation of skyrmions in 4 ns at zero field using a 1.4×10^{12} Am⁻² density, 5 ns long current pulse is possible via SOT-induced local switching in a Pt/Co68B32/Ir microwire. A square current pulse was injected through a 500 nm wide Cu injector fabricated on top of the magnetic wire. The skyrmion was annihilated using an oersted field generated from an Omega coil which was fabricated in the vicinity of the injector. This set up enabled us to used time resolved microscopy to study the sub-nanosecond dynamics with a time resolution of 200 ps⁵¹(Fig. 2(d)). The nucleation was highly deterministic and the size of the nucleated skyrmion was determined in part by the total amount of charge in the current pulse, as well as, the length of the current pulse. No measurable delay was observed between the electrical excitation and the nucleation of a single skyrmion. Furthermore, we observed that that in the absence of static external magnetic fields, the four possible combinations of

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FIG. 2. Electrical nucleation of skyrmions in heterostructures. (a) Néel-type skyrmion nucleated using a current pulse from a geometrical constriction. From Ref. 15. Reprinted with permission from AAAS. (b) Electrical nucleation at pinning sites. Reprinted by permission from Springer Nature from Ref. 46. Copyright 2018. (c) Deterministic nucleation of skyrmions using a nanocontact. Reproduced under CC-BY license from Ref. 49. (d) Time resolved investigation of skyrmion nucleation from a point contact. Reprinted (adapted) with permission from Ref. 51. Copyright 2019 American Chemical Society.

nucleation current direction and annihilation field direction are symmetric. Both observations are indicative of SOT influenced magnetic switching. Dynamical heating of the microwire during the current pulse was seen to play a role in the magnetization reversal by raising the temperature of the wire during the pulse close to the Curie temperature (measured to be 475 K) and thus lowering the threshold current density needed to nucleate a skyrmion. The change in temperature during the current pulse was determined by correlating the magnetization dependent contrast change in the saturated area of the wire with the known saturation magnetization change of the multilayer (measured using SOUID-vibrating sample magnetometry). During the 5 ns pulse the temperature was seen to increase to around 420-440 K. Skyrmion nucleation can be even faster. Nucleation at the picosecond timescale was later demonstrated via femtosecond laser pulses which demonstrated to be mediated by high-temperature topological fluctuation state in which skyrmions are created by homogeneous nucleation52.

An alternative way of nucleating skyrmions at precise, customized locations is by artificially changing the magnetic energy landscape and breaking the symmetry of the system by, for example,introducing defects such as local fluctuations of the anisotropy. A process first suggested separately by Büttner *et al.*⁵³ and Everschor-Sitte *et al.*⁵⁴ in 2017. We have shown that focused ion beam (FIB) irradiation enables the localized and deterministic nucleation of skyrmions under external out of plane field cycling⁵⁵. Ion irradiation is well-documented to both reduce the perpendicular anisotropy and increase the coercivity in a dose-dependent manner. This deterministic manipulation of the magnetic properties has multiple advantages (1) it enables the localization of nucleation, (2) it stabilizes skyrmions over a larger range of external field strengths, including stability at zero field, and (3) it enables the existence of skyrmions in materials systems where, prior to defect fabrication, skyrmions were not previously observed through field cycling alone. By carefully tuning the artificial defect it is possible to promote nucleation of skyrmions without changing the equilibrium diameter of the skyrmion. FIB defects were created using a FEI Nova NanoLab 200 SEM and FIB with a 30 keV Ga⁺ beam energy and beam current of 10 pA resulting in an ion beam diameter of 10 nm. Irradiation doses between 10^{14} and 10^{18} ions per cm² were delivered to the sample. Intermixing of the top layers of the multilayer was observed at doses above 5×10^{16} ions per cm² with structural damage being introduced at doses above 10¹⁷ ions per cm². At the optimum doses, 100% skyrmion nucleation was observed without affecting the skyrmion diameter. The observed mean skyrmion diameter at zero field was measured to be 170 ± 30 nm nucleated at 5×10^{16} ions per cm² defects and 180 ± 30 nm at 1×10^{17} ions per cm² defects. From structural imaging, these ion irradiation doses were associated with a 100 nm diameter area of damage. More recently, it was shown that similar effects can be achieved using He⁺ irradiation. By lowering the out of plane anisotropy and DMI strength locally along linear tracks it was shown that skyrmions were preferentially nucleated and move along the 'designer' tracks and with this a suppression of the skyrmion Hall effect was achieved⁵⁶. Initial studies have expanded this concept towards active anisotropy control via strain engineering (in this instance via temperature). This is an exciting first step towards developing strain-assisted skyrmion-based memory and logic devices⁵⁷. Strain manipulation is an innovative solutions for devices of the future which reduces energy dissipation and the risk of heightened temperatures within the device caused by current pulses58

B. Propagation

The first experimental demonstration of the electrically driven motion of skyrmions at ambient temperatures was reported by Woo *et al.* in Pt/Co/Ta and Pt/CoFeB/MgO-based multilayer microwires under an applied out-of-plane field¹⁶. Velocities of 46 ms⁻¹ at current densities $J \sim 3.5 \times 10^{11}$ Am⁻² were observed. Jiang *et al.* showed the skyrmion Hall angle, Θ_{sk} , evolution with velocity in Ta/CoFeB/TaO_x trilayers at velocities < 1 ms⁻¹ and an external magnetic field⁴⁰. Following the modified Thiele equation for rigid skyrmions, Θ_{sk} is expected to depend on the skyrmion diameter *d*, given by tan $\Theta_{sk} = v_y/v_x = -Q/\alpha \mathscr{D}$, where v_y and v_x are the velocity of the skyrmion along *y* and *x*, respectively. The geometrical factor $\mathscr{D} = \pi 2d/8 \gamma_{km}$, where γ_{km} is the width of the

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domain wall surrounding the skyrmion⁴⁰. Note that this approach predicts that Θ_{sk} is independent of the driving force or velocity of the skyrmion, in contradiction to the experimental findings of both this group⁴⁰ and the work of Litzius et al.⁴¹ This is because an idealistic flat energy landscape is assumed and therefore there is no pinning force term in this form of the Thiele equation.

An early indication of the importance of the materials system and the amount of inhomogeneities and pinning sites present with respect to skyrmion motion (as well as nucleation Woo et al.⁴⁶) was observed in Woo et al.'s work in 2016¹⁶. In our own work on skyrmion motion we elaborated on this by demonstrating the skyrmion motion at zero field in a metallic CoB-based multilayer material system. We showed that the influence of inhomogeneities and skyrmionskyrmion repulsion on the skyrmion motion driven by current pulses is crucial in understanding the observed skyrmion Hall angle⁵⁹. We tracked hundreds of skyrmions with diameters ranging from 35 to 825 nm with an average velocity ¹. We observed a diameter independent average of 6+1 ms⁻ skyrmion Hall angle of $9^{\circ}\pm 2^{\circ}$ (Fig. 3(a)). This showed experimentally that in material systems with pinning and inhomogeneities the diameter dependence of the skyrmion Hall effect is washed out and the direction of motion is often dominated, not by the topology, but by the micromagnetic environment⁵⁹(Fig. 3(b)). Furthermore, in the high skyrmion density regime, collective motion takes place where the presence of interfacial spin transfer torques can also weaken the diameter dependence⁶⁰. Our experimental observations reproduce principles shown in skyrmion motion models and micromagnetic simulations throughout the literature 61,62 (Fig. 3(c)). In addition it was shown that in multilayer systems it is crucial to consider the non-rigidity of the skyrmion during the current pulse. Dependent on the current density it is possible to observe skyrmion shape deformation which occur during the current pulses when using moderate current densities as well as skyrmion domain wall deformation which occurs at large current densities. Both phenomena affect the skyrmion Hall angle41,63,64

In more recent publications further engineering of the magnetic energetic via careful tuning of the heterostructure materials design has paved the way towards skyrmion motion which is driven⁶⁵ and controlled by thermal and tempera-ture gradients⁶⁶. Studies in bulk systems, such as MnSi, showed thermally-activated skyrmion-lattice-creep with important consequences for motion occurring at low J^{67} .

C. Detection

Electrical detection is a key requisite for any skyrmion spintronics application. More fundamentally, owing to the non-trivial topology, the way a skyrmion interacts with electrons traversing it leads to a rich emergent electrodynamics³³. As outlined in the introduction a magnetic system containing skyrmions is expected to result in three distinct and dominant contribution to its resistance: 1) the ordinary Hall effect experienced by all conducting materials, 2) the anomalous Hall



FIG. 3. Electrically driven motion of skyrmions in heterostructures. (a) Diameter dependence of skyrmion Hall angle in an imperfect heterostructure. Reproduced under CC-BY license from Ref. 59. (b) Left, average intensity map of STXM images. Bright regions show areas with higher probability of skyrmion occurrence probability of containing a reversed magnetic domain or skyrmion. Middle, average intensity map of the absolute difference between consecutive images. Bright regions show high probability of a moving skyrmion. Reproduced under CC-BY license from Ref. 59. (c) Simulated path taken by skyrmions moving at low velocity in a system containing an array of defects. Reproduced under CC-BY license from Ref. 61.

resistance which is proportional to the systems out-of-plane magnetization, and 3) the topological Hall resistance. We can therefore write that $\rho_{xy} = R_{\rm H}B + R_{\rm S}\mu_0M + R_{\rm H}PB_{\rm e}$, where $R_{\rm S}$ is the anomalous Hall coefficient (see figure Fig. 4(a)).

Looking at the electrical detection it was shown by Maccariello et al. that skyrmions can be measured using the anomalous Hall effect. A electrical signature of a single skyrmion with a diameter of < 100 nm was measured to be of the order of $3.5 \pm 0.5 \text{ n}\Omega\text{cm}^{47}$. However, using the anomalous Hall resistance in systems where the skyrmion size is not constant is open to interpretation errors if the skyrmion diameter is not uniform, as differentiating between a large skyrmion and multiple smaller skyrmions is impossible if the ratio of antiparallel aligned magnetized domains is identical. In principle, the topological Hall effect allows us to make this distinction. For example, in FeGe nanostructures containing a magnetic crystal of skyrmions the quantized jump associated with each skyrmion was measured to be ~ 10 n Ω cm⁶⁸. In interfacial skyrmion systems similar skyrmion number-dependent contributions have been observed. Soumyanarayamanan et al. published a skyrmion density dependent resistivity contribution of $\rho_{xy} = 30 \text{ n}\Omega \text{cm}$ in films of Ir/Fe/Co/Pt heterostructures12. Our work in Pt/Co/Ir multilayer systems showed that there is indeed a skyrmion number dependent quantized resistivity contribution in interfacial Neel skyrmions of 22 ± 2 n Ω cm. We measured the resistivity of individual skyrmions in a disc while simultaneously imaging the out-of-plane magnetization⁴⁵ (see figure Fig. 4(b)-(e)). However, this is three magnitudes larger

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than the expected topological Hall resistivity using the Berry phase theory developed for bulk systems (discussed in the introduction) which predicts a contribution of 0.01 $n\Omega cm$ per skyrmion, a conclusion that was mirrored and expanded upon in Raju et al.'s study in 201969. The latest development in the investigation of this phenomenon was published in 2021 by Raju et al., who showed that the unusually large topological resistivity values are measured for isolated skyrmions whereas dense skyrmion arrays result in smaller topological resistivities 70 (see figure Fig. 4(f)). A close link between the phase boundary of a dense skyrmion crystal and an isolated skyrmion system and the topological Hall effect was observed leading to a peak of the topological contribution followed by a sharp decline as all skyrmions are annihilated within the material system. A strong dependence on the stability parameter $\kappa = \pi D / (4 \sqrt{A K_{\text{eff}}})$ was found. A value of $\kappa < 1$ represents a disordered metastable skyrmion phase and a $\kappa \geq 1$ represents a skyrmion lattice phase. Field and temperature was used to show the dependence of the topological Hall signal on κ by driving the material system from the skyrmion lattice phase into the isolated skyrmion phase and vice versa. The complicated relationship between the topological Hall resistivity theory and the measurements in heterostructures is emphasized by Fig. 4(g) which shows a linear dependence of the topological Hall resistivity with temperature and skyrmion density. Furthermore, Fig. 4(h) shows a less then 25% change in the topological Hall resistivity while the ordinary Hall coefficient changes sign⁶⁹. Raju et al. concluded that chiral spin fluctuations at all length scales which occur at the phase boundary causes the colossal magnitudes of the topological Hall effect in chiral magnetic heterostructures⁷⁰. Other chiral scattering effects have been predicted by Lux et al.71 and Fujishiro et al.72, with the latter also being used to account for the observation of a giant anomalous Hall effect in a MnGe thin film. Studying the relevance of thee new mechanisms to skyrmion spintronic materials is a future direction for research. For practical applications however, larger changes in resis-

For practical applications however, larger changes in resistivity are desirable. For this, magnetic tunnel junctions are a powerful sensing device for skyrmions. In 2019 it was shown that a single skyrmion with a diameter less than 100 nm resulted in a change in the magnetic tunnel junction resistance of around 10%⁷⁴.

IV. OUTLOOK

The field of skyrmion spintronics continues to be a lively one with many open questions to answer and active avenues of research to pursue. For instance, in term of materials and pinning - what are the desired parameters for different applications? CMOS-compatibility imposes a lot of requirements and restrictions with regards to what materials are feasible and how they are grown. Other applications might be more open. Post materials growth refinement is an interesting avenue with many possibility. For example, it has recently been shown that He irradiation can be used to locally reduce pinning, allowing the creation of tracks along which skyrmions propagate⁵⁶ (see Fig. 5(a)).



(a)

cm)

tom panel shows the different contribution to the resistivity (Ordinary Hall resistivity, anomalous Hall resistivity and topological Hall resistivity). reprinted with permission from Ref. 73. Copyright 2013 by the American Physical Society. (b)-(d) scanning transmission x ray microscopy showing the out of plane magnetic contrast of one, two and three skyrmions in an electrically connected disk (light and dark contrast show antiparallel aligned magnetic domains)⁴⁵. (e) A quantized contribution to the resistivity, ρ_{xy}^{int} , which is independent of the magnetization but dependent on the number of skyrmions within the disk, the slope shows the skyrmion size dependent anomalous Hall resistance which is directly proportional to the ratio between the up and down magnetized domains⁴⁵. The inset shows that the skyrmion number dependent contribution becomes significant for skyrmions with radius below around 125 nm (f)-(g) Magnetic force microscopy images of a Ir/Fe/Co/Pt multilayer system driven from the skyrmion lattice into the metastable isolated skyrmion phase and the measured increase in the topological Hall contribution. Reproduced under CC-BY license from Ref. 70. (g) Temperature dependence of the skyrmion density with temperature and the measured resistivity contribution not accounted for by the ordinary Hall resistivity and the anomalous Hall resistivity at -0.3 T $\Delta \rho_{xy}$. (h) Magnitude of the topological Hall resistivity peaks at negative (squares) and positive fields (circles) (left axis) in comparison to the temperature evolution of the ordinary Hall coefficient R₀ (right axis). Reproduced under CC-BY license from Ref. 69.

In the previous section we have principally discussed manipulating skyrmions using spin-orbit torques. Nevertheless, other forms of electrical nucleation and propagation are possible. For instance, micron-scale skyrmion bubbles were observed to appear in a Pt/Co/oxide trilayer beneath an indium tin oxide electrode when +20 V was applied⁷⁹, attributed to a voltage-driven change in the Curie temperature causing a modulation of M_s . In similar experiment using a multilayer with a lateral thickness gradient, the application of a voltage caused skyrmions to both appear and then begin to move along the gradient direction⁸⁰. In modelling this process it was assumed that the voltage causes changes in the PMA, an This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset

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FIG. 5. What does the future hold for the field of skyrmion research? (a) Putting skyrmions on track using helium ion irradiation. Reprinted (adapted) with permission from Ref. 56. Copyright 2021 American Chemical Society. (b) Moving towards smaller skyrmions stable at room temperature. Reprinted by permission from Springer Nature from Ref. 75, copyright 2018. (c) Discovering new materials supporting antiskyrmions. Reprinted by permission from Springer Nature from Ref. 76, copyright 2017. (d) Entering the rich space of three dimensional topological quasi particles with hopfions. Reproduced under CC-BY license from Ref. 77. (e) Using skyrmions for non-von Neumann computing hardware. Reprinted by permission from Springer Nature from Ref. 78, copyright 2020.

effect that has come to be known as voltage-controlled magnetic anisotropy (VCMA). VCMA has been exploited to create and annihilate skyrmions by means of nanosecond voltage pulses in a magnetic tunnel junction that was used to detect them by tunneling magnetoresistance⁸¹, or to create and annihilate skyrmions at zero field in a multilayer in which an antiferromagnetic layer was used to apply an effective field using exchange bias⁸². Simulations have been used to show that the VCMA effect is suitable for operating voltage controlled memory elements based on skyrmions that are potentially much more energy efficient than alternatives based on spin-orbit torques⁸³.

As well as the direct effects of electric fields on magnetic properties, there are indirect effects such as those mediated by strain via the electric field induces strain in a piezoelectric material that forms an interface with the magnetic layer of interest. Transfer of strain across the interface induces magnetic effects through magnetostriction. Simulations of magnetic nanodisks showed that strain-mediated nucleation and annihilation of skyrmions is possible, as well as controlling a range of other topological transitions between skyrmions, vortices, merons, and skyrmioniums⁸⁴. In another simulation,

a single stable skyrmion was created and stabilized by a vertical strain pulse applied to a Pd/Fe/Ir hybrid structure generated by a piezo electron Pb($Zr_{1-x}Ti_x$)O₃ nanowire⁸⁵. In a more advanced approach, which takes account of biaxial as well as uniaxial strain, a combination of multiscale modeling and Lorentz microscopy was used to demonstrate deterministic control over topological spin textures in magnetic thin films⁸⁶. An interesting form of applying a non-uniform strain is the traveling strain wave known as a surface acoustic wave (SAW). Simulations incorporating magnetoelastic phenomena show that skyrmions can move in response to SAWs⁸⁷. Furthermore, there is now an experimental report of skyrmions being created using SAWs⁸⁸.

How small can skyrmions be made? High density storage applications rely on having the smallest possible bit sizes. Whilst nanometer-scale skyrmions are possible in epitaxial ferromagnetic monolayers at cryogenic temperatures⁸⁹, theoretical considerations point to low or zero moment materials as offering the best opportunities for success at room temperature⁹⁰. One approach is to use rare earth-transition metal ferrimagnetic alloys close to their compensation point, where skyrmions approaching sizes as small as 10 nm have been observed⁷⁵ (see Fig. 5(b)). An additional benefit of these materials is the suppressed skyrmion Hall effect⁴⁶ (predicted by theory by Barker *et al.*⁹¹), due to the cancellation of the equal and opposite topological charges on the two sublattices.

However, one drawback of this approach is the relatively narrow window of operating temperatures which is restricted to a small region around the compensation point. Given the experimental difficulties of working with true antiferromagnets, another way of achieving a net zero magnetization is to use synthetic antiferromagnets^{90,92} where pairs of equal moment ferromagnetic layers are coupled though spacers that provide an antiferromagnetic indirect exchange interaction⁹³. Recent experiments have separately shown shown, that skyrmions in such systems can be small⁹⁴, dense⁹⁵, and have negligible skyrmion Hall effect⁹⁶.

How else can skyrmions be stabilized other than the DMI? Much recent activity has focused on the idea of frustration being another mechanism^{97–99}. The dynamics of skyrmions stabilized by this method has been studied by micromagnetic simulation^{100,101}. Experimentally, a promising material for studying these phenomena is the frustrated kagomé ferromagnet Fe₃Sn₂, which has been shown to host skyrmions at room temperature⁸. The fact that there is no DMI to enforce a single chirality for these skyrmions means that the two possible chiral states might be used to represent a digital 0 and 1 rather than presence and absence. Bit control is achieved through the current-driven helicity switching^{100,102}. Experimental progress already shows promise for memories¹⁰³, where the unusually large topological Hall effect in this material might be useful for readout¹⁰⁴.

What other topological spin textures could provide spintronic functionality? Other topological objects, e.g. antiskyrmions, skyrmioniums, and hopfions, are coming to the attention of researchers working in magnetism¹⁰⁵. An anisotropic DMI can lead to the formation of antiskyrmions¹⁰⁶, where the form oscillates twice between

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Bloch and Néel as the edge of the structure is traversed. Lattices of antiskyrmions have been observed in ferromagnetic $Mn_{1.4}Pt_{0.9}Pd_{0.1}Sn^{76}$, ferrimagnetic $Mn_2Rh_{0.95}Ir_{0.05}Sn^{107}$ (see Fig. 5(c)), and Fe_{1.9}Ni_{0.9}Pd_{0.2}P¹⁰⁸. Clever selection of the current direction with respect to the DMI anisotropy axes can be used to control their direction of motion^{108,109}. Furthermore, they generate topological Hall signals in the same way as skyrmions¹¹⁰.

A skyrmionium is one skyrmion contained within another of opposite topological charge¹¹¹ and hence possesses zero net gyrovector¹¹². These structures are also known as target skyrmions. Simulations show that they have distinctive current-¹¹³ and field-driven dynamics¹¹⁴ and have recently been observed in FeGe nanodiscs¹¹⁵.

In three-dimensions, skyrmion tubes that are twisted into rings and knots known as hopfions have been predicted to exist, possessing their own topological index called the Hopf charge¹¹⁶. Micromagnetic modeling shows that these can be expected to be stabilized in chiral magnetic nanodiscs^{116,117}. The same approach has been used to model the dynamics. Whilst there is no gyrovector ($\mathbf{G} = 0$) and therefore no equivalent of the skyrmion Hall effect is to be expected, the dynamics is rich! It is predicted that the form of the hopfion (Néel or Bloch-like) will affect the direction of travel under current drive¹¹⁸. The three-dimensional nature of these objects means that other degrees of freedom such as rotation and dilation are also available¹¹⁹. Very recently, a simple form of a hopfion has been experimentally detected in multilayer nanodisc in which the ferromagnetic Co layer thickness was varied to give a depth dependent magnetic anisotropy⁷⁷ (see Fig. 5(d)).

Beyond the ubiquitous racetrack memory concept^{120,121}, what possible applications might there be that use the unique properties of skyrmions? Various proposals for skyrmionbased logic architectures exist which can perform Boolean operations¹²², can be reconfigurable¹²³, and provide reversible computing¹²⁴ or logic-in-memory operation¹²⁵.

Unconventional (non-von Neumann) computing is rapidly becoming one of the most promising application areas for spintronics, with neuromorphic computing being a particular focus¹²⁶. A proposal for the use of a skyrmion gas for probabilistic computing¹²⁷ was recently realized experimentally⁶⁵. Combining this concept with logic-style networks allows for stochastic computing using skyrmions¹²⁸. Meanwhile, related skyrmion textures are potentially useful for reservoir computing^{129,130} and random number generation¹³¹. The unique properties of skyrmions have also been proposed as a means to realize synaptic devices^{132,133}. The current-driven nucleation, propagation, and detection of skyrmions has been shown to mimic synaptic potentiation and depression in a ferrimagnetic nanoscale device suitable for neuromorphic applications such as image recognition⁷⁸ (see Fig. 5(e)). Skyrmion networks can be used to provide a solution to the shortest path problem¹³⁴.

There are also possibilities in the realm of quantum technology. A skyrmion-bearing layer placed on top of a superconductor is predicted to host a Majorana bound state at its core^{135,136} or to generate Majorana bands around the edge of the skyrmion¹³⁷. Suitable materials systems have already been fabricated¹³⁸. For sufficiently small skyrmions the chirality can possess quantum dynamics¹³⁹, leading to a recent proposal that skyrmions can be used as qubits¹⁴⁰.

From this rich variety of current and future research directions, it is clear that skyrmion spintronics will continue to be an active and vibrant field for many years to come.

ACKNOWLEDGMENTS

This work was supported by the UK EPSRC (grant number EP/T006803/1) and the project 17FUN08 TOPS, which has received funding from the EMPIR programme co-financed by the Participating States and from the European Union's Horizon 2020 research and innovation programme.

DATA AVAILABILITY

Data sharing is not relevant to this article as no new data were created or analyzed in writing it.

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